P-Channel 60-V (D-S) MOSFET

Key Features:

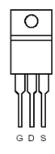
- Low r_{DS(on)} trench technology
- · Low thermal impedance
- · Fast switching speed

Typical Applications:

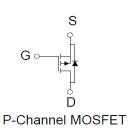
- White LED boost converters
- · Automotive Systems
- Industrial DC/DC Conversion Circuits

PRODUCT SUMMARY				
V _{DS} (V)	$r_{DS(on)}(m\Omega)$	I _D (A)		
-60	20 @ V _{GS} = -10V	-45		
	28 @ V _{GS} = -4.5V	-38		





TO-220CFM



Top View

ABSOLUTE MAXIMUM RATINGS (T _A = 25°C UNLESS OTHERWISE NOTED)						
Parameter		Symbol	Limit	Units		
Drain-Source Voltage		V_{DS}	-60	V		
Gate-Source Voltage		V_{GS}	±20	V		
Continuous Drain Current a	T _C =25°C	I _D	-45	Α		
Pulsed Drain Current ^b		I _{DM}	-180	A		
Continuous Source Current (Diode Conduction) a	T _C =25°C	I _S	-45	Α		
Power Dissipation ^a	T _C =25°C	P_D	60	W		
Operating Junction and Storage Temperature Range		T_J , T_{stg}	-55 to 175	°C		

THERMAL RESISTANCE RATINGS					
Parameter	Symbol	Maximum	Units		
Maximum Junction-to-Ambient °	$R_{\theta JA}$	62.5	°C/W		
Maximum Junction-to-Case	$R_{\theta JC}$	0.29	C/VV		

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Notes

- a. Package Limited
- b. Pulse width limited by maximum junction temperature
- c. Surface Mounted on 1" x 1" FR4 Board.

Electrical Characteristics

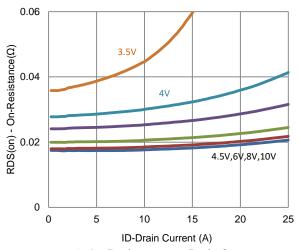
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Static							
Gate-Source Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_{D} = -250 \text{ uA}$				V	
Gate-Body Leakage	I_{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			±100	nA	
Zara Cata Valtara Brain Comment	l	$V_{DS} = -48 \text{ V}, V_{GS} = 0 \text{ V}$			-1	uA	
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = -48 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			-10	uA	
On-State Drain Current ^a	$I_{D(on)}$	$V_{DS} = -5 \text{ V}, V_{GS} = -10 \text{ V}$	-110			Α	
Drain Course On Besistance a	r	$V_{GS} = -10 \text{ V}, I_D = -20 \text{ A}$			20	mΩ	
Drain-Source On-Resistance ^a	r _{DS(on)}	$V_{GS} = -4.5 \text{ V}, I_D = -16 \text{ A}$			28		
Forward Transconductance ^a	g_{fs}	$V_{DS} = -15 \text{ V}, I_{D} = -20 \text{ A}$		10		S	
Diode Forward Voltage ^a	V_{SD}	$I_S = -20 \text{ A}, V_{GS} = 0 \text{ V}$		-0.9		V	
	Dynamic ^b						
Total Gate Charge	Q_g	$V_{DS} = -30 \text{ V}, V_{GS} = -4.5 \text{ V},$		22		nC	
Gate-Source Charge	Q_gs	$V_{DS} = -30 \text{ V}, V_{GS} = -4.3 \text{ V},$ $I_{D} = -20 \text{ A}$		10			
Gate-Drain Charge	Q_gd	1 _D = 20 /1		9.3			
Turn-On Delay Time	$t_{d(on)}$	V 20 V D = 15 O		9			
Rise Time	t _r	$V_{DS} = -30 \text{ V}, R_{L} = 1.5 \Omega,$ $I_{D} = -20 \text{ A},$		9		no	
Turn-Off Delay Time	$t_{d(off)}$	$V_{GEN} = -10 \text{ V}, R_{GEN} = 6 \Omega$		85		ns	
Fall Time	t _f	VGEN - 10 V, NGEN 0 12		27			
Input Capacitance	C _{iss}			4464			
Output Capacitance	C _{oss}	$V_{DS} = -15 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ Mhz}$	_	216		pF	
Reverse Transfer Capacitance	C_{rss}			163			

Notes

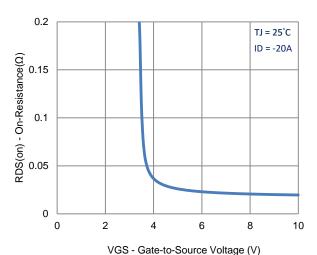
- a. Pulse test: PW <= 300us duty cycle <= 2%.
- b. Guaranteed by design, not subject to production testing.

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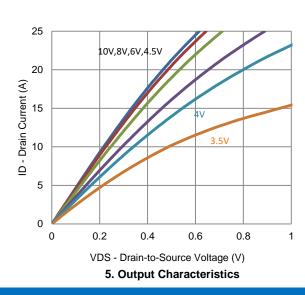
Typical Electrical Characteristics



1. On-Resistance vs. Drain Current



3. On-Resistance vs. Gate-to-Source Voltage



20
TJ = 25°C

(V) 15
Logical TJ = 25°C

TJ = 25°C

2

0

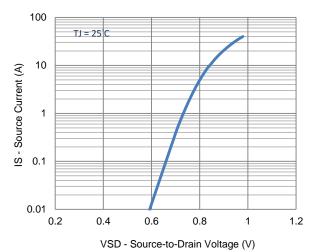
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VGS - Gate-to-Source Voltage (V)
2. Transfer Characteristics

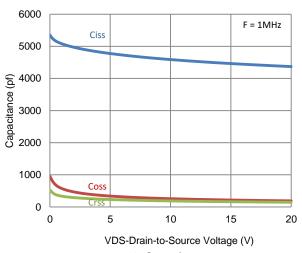
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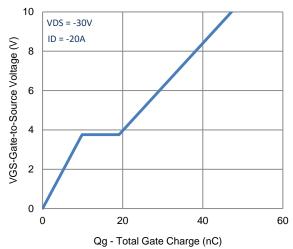
4. Drain-to-Source Forward Voltage

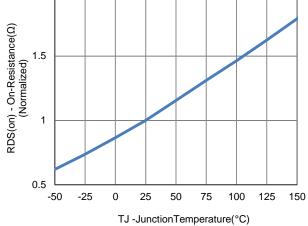


6. Capacitance

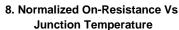
Typical Electrical Characteristics

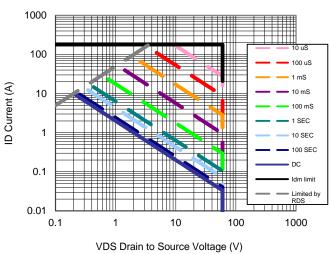
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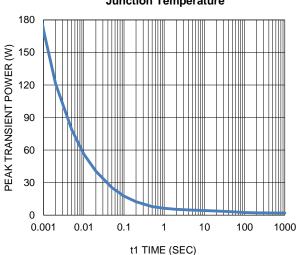




7. Gate Charge

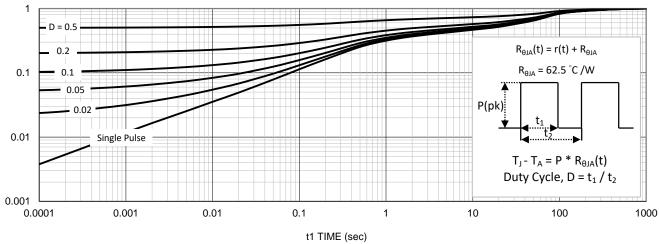






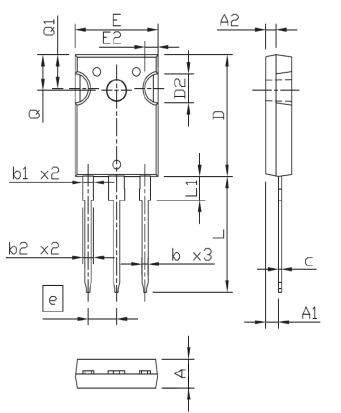
9. Safe Operating Area

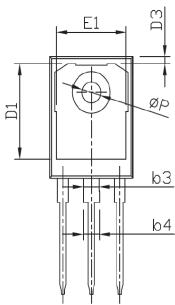
10. Single Pulse Maximum Power Dissipation



11. Normalized Thermal Transient Junction to Ambient

Package Information





CVMDEI C	DIMENSIONS IN MILLIMETERS				
SYMBOLS	MIN	NDM	MAX		
Α	4,90	5,00	5,10		
A1	2.32	2.42	2.52		
A2	1,90	2.00	2,10		
b	1.17	1.22	1.27		
b1	1.97	2.02	2.07		
b2	2.00	2.10	2.20		
b3	2.97	3.02	3.07		
b4	3.00	3.10	3.20		
С	0.59	0.62	0.66		
D	20,90	21.00	21.10		
D1	16,25	16.55	16.85		
D2	5,00 TYP				
D3	1.05	1.20	1.35		
е		<u>5.44 BS(</u>)		
e E	15.70	15.80	15.90		
E1	13.06	13.26	13.46		
E2	2,50 TYP				
L	19.72	19.92	20.12		
L1			4,30		
Q	6.15 BSC				
Q1	5.60	5.80	6.00		
ØΡ	3,55	3,60	3,65		